NSN 5961-01-287-5657

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-287-5657
Inclosure Material: Metal
Overall Length:
0.535 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.559 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
500.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
15.00 amperes forward current, total rms horsepower metric
Power Rating Per Characteristic:
10.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: pnpn
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:

Filg:

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